

SEMICONDUCTOR

2N3820

P-Channel General Purpose Amplifier

- This device is designed primarily for low level audio and general purpose applications with high impedance signal sources.
- Sourced from process 89.



1. Drain 2. Gate 3. Source

PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings* T_C=25°C unless otherwise noted

| Symbol | Parameter | Ratings | Units |
|------------------|--|-----------|-------|
| V _{DG} | Drain-Gate Voltage | -20 | V |
| V _{GS} | Gate-Source Voltage | 20 | V |
| I _{GF} | Forward Gate Current | 10 | mA |
| T _{STG} | Storage Temperature Range | -55 ~ 150 | °C |
| | g values above which the serviceability of any semiconductor device may be impaired. | 1 | |

NOTES:

1) These rating are based on a maximum junction temperature of 150 degrees C.
2) These are steady limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Electrical Characteristics T_C=25°C unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units | |
|-----------------------|-----------------------------------|---|------|------|------|-------|--|
| Off Characteristics | | | | | | | |
| V _{(BR)GSS} | Gate-Source Breakdwon Voltage | $I_{G} = 10\mu A, V_{DS} = 0$ | 20 | | | V | |
| I _{GSS} | Gate Reverse Current | $V_{GS} = 10V, V_{DS} = 0$ | | | 20 | nA | |
| V _{GS} (off) | Gate-Source Cutoff Voltage | $V_{DS} = -10V, I_{D} = -10\mu A$ | | | 8.0 | V | |
| On Chara | cteristics | | | | | | |
| I _{DSS} | Zero-Gate Voltage Drain Current * | $V_{DS} = -10V, V_{GS} = 0$ | -0.3 | | -15 | mA | |
| Small Sig | nal Characteristics | · | | | | | |
| gfs | Forward Transfer Conductance | $V_{DS} = -10V, V_{GS} = 0, f = 1.0KHz$ | 800 | | 5000 | μmhos | |
| C _{iss} | Input Capacitance | $V_{DS} = -10V, V_{GS} = 0, f = 1.0KHz$ | | | 32 | pF | |
| C _{rss} | Reverse Transfer Capacitance | $V_{DS} = -10V, V_{GS} = 0, f = 1.0KHz$ | | | 16 | pF | |

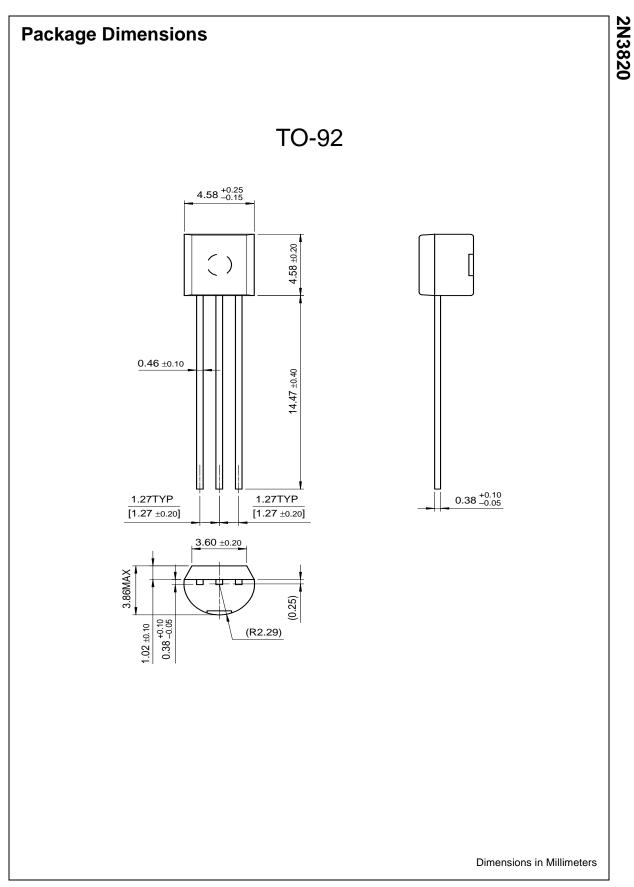
* Pulse Test: Pulse Width \leq 300ms, Duty Cycle \leq 2%

Thermal Characteristics T_A=25°C unless otherwise noted

| Symbol | Parameter | Max. | Units |
|-----------------------|---|------|-------|
| PD | Total Device Dissipation | 350 | mW |
| | Derate above 25°C | 2.8 | mW/°C |
| $R_{	extsf{	heta}JC}$ | Thermal Resistance, Junction to Case | 125 | °C/W |
| $R_{	extsf{	heta}JA}$ | Thermal Resistance, Junction to Ambient | 357 | °C/W |

Device mounted on FR-4 PCB 1.6" \times 1.6" \times 0.06'

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PRODUCT STATUS DEFINITIONS

Definition of Terms

| Datasheet Identification | Product Status | Definition |
|--------------------------|---------------------------|---|
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